

PSMN3R5-40YSD

N-channel 40 V, 3.5 m Ω , 120 A standard level MOSFET in LFPAK56 using NextPower-S3 Schottky-Plus technology

Product data sheet

1. General description

120 A, standard level gate drive N-channel enhancement mode MOSFET in 175 °C LFPAK56 package using advanced TrenchMOS Superjunction technology. This product has been designed and qualified for high performance power switching applications.

2. Features and benefits

- 120 A capability
- Avalanche rated, 100% tested at $I_{(AS)} = 120 \text{ A}$
- NextPower-S3 technology delivers 'superfast switching with soft recovery'
- Low Q_{RR}, Q_G and Q_{GD} for high system efficiency and low EMI designs
- Schottky-Plus body-diode, gives soft switching without the associated high I_{DSS} leakage
- Low V_{SD} Schottky-like body-diode
- Tighter V_{GS(th)} limits for improved paralleling
- Wide Safe Operating Area (SOA) for reliable linear mode operation
- High reliability LFPAK (Power SO8) package, copper-clip, solder die attach and qualified to
- Exposed leads can be wave soldered, visual solder joint inspection and high quality solder joints

3. Applications

- Synchronous rectification
- DC-to-DC converters
- High performance and high efficiency power supplies
- **BLDC** motor control

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	120	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	115	W
Tj	junction temperature			-55	-	175	°C
Static characte	ristics			•			
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 10		-	3	3.5	mΩ
Dynamic chara	Dynamic characteristics						



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q _{G(tot)}	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 20 \text{ V}; V_{GS} = 10 \text{ V};$	-	31	44	nC
Q_{GD}	gate-drain charge	Fig. 12; Fig. 13	-	5	10	nC

^{[1] 120}A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	D
2	S	source	<u> </u>	
3	S	source	a	G (F)
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	1 2 3 4 LFPAK56; Power- SO8 (SOT669)	

6. Ordering information

Table 3. Ordering information

Type number Package						
	Name	Description	Version			
PSMN3R5-40YSD	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669			

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN3R5-40YSD	3D5S40Y

8. Limiting values

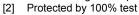
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	40	V
V_{DSM}	peak drain-source voltage	$t_p \le 20 \text{ ns}; f \le 500 \text{ kHz}; E_{DS(AL)} \le 200 \text{ nJ};$ pulsed		-	45	V
V_{DGR}	drain-gate voltage	$25 ^{\circ}$ C ≤ T _j ≤ 175 $^{\circ}$ C; R _{GS} = 20 kΩ		-	40	V
V_{GS}	gate-source voltage	T _j ≤ 175 °C		-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	115	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	120	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	93	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 \text{ °C}$; Fig. 3		-	526	А

					101	
Symbol	Parameter	Conditions		Min	Max	Unit
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	n diode					
Is	source current	T _{mb} = 25 °C		-	96	Α
I _{SM}	peak source current	pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C		-	526	Α
Avalanche ru	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 39.7 A; $V_{sup} \le 40$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 141 μs	[2]	-	145	mJ
		I_D = 25 A; $V_{sup} \le 40$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 374 μs		-	243	mJ
I _{AS}	non-repetitive avalanche current	V_{sup} = 40 V; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; R_{GS} = 50 Ω	[2]	-	120	Α

^{[1] 120}A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.



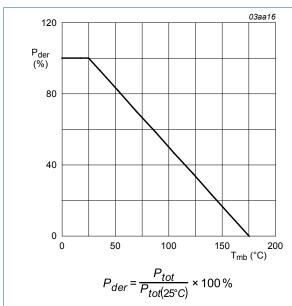
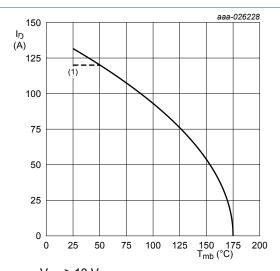
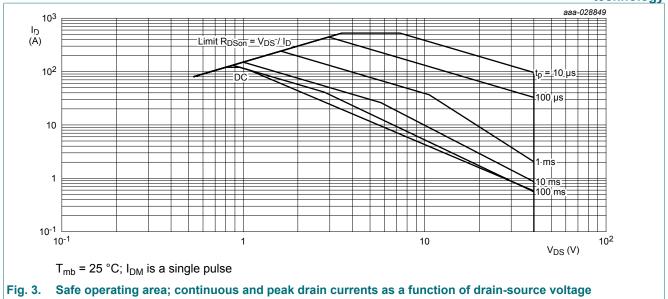


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



V_{GS} ≥ 10 V (1) 120A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design

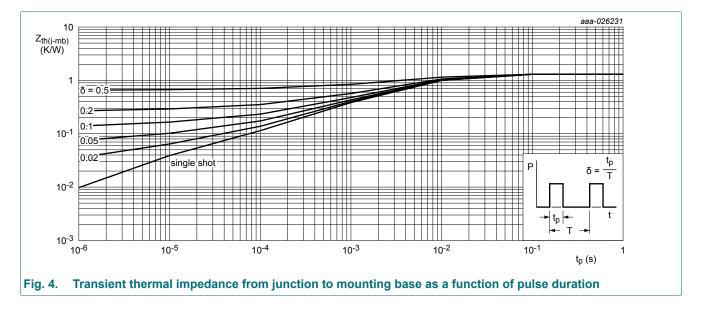
and operating temperature.



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	1.18	1.3	K/W
R _{th(j-a)} thermal resistance from junction to ambient	thermal resistance from	Fig. 5	-	42	-	K/W
	junction to ambient	Fig. 6	-	85	-	K/W



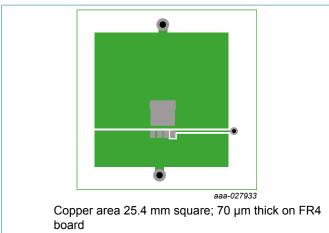
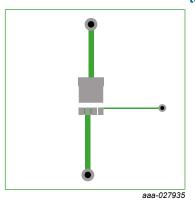


Fig. 5. PCB layout for thermal resistance from junction to ambient



70 µm thick copper on FR4 board

Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	cteristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	40	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	36	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	2.4	3.1	3.6	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-6.46	-	mV/K
I _{DSS}	drain leakage current	$V_{DS} = 32 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	0.016	1	μΑ
		V _{DS} = 32 V; V _{GS} = 0 V; T _j = 125 °C	-	2.19	-	μΑ
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 10	-	3	3.5	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 175 °C; Fig. 11	-	-	6.7	mΩ
R_G	gate resistance	f = 1 MHz; T _j = 25 °C	0.3	0.8	2	Ω
Dynamic cha	aracteristics			'		
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 20 V; V _{GS} = 10 V; Fig. 12; Fig. 13	-	31	44	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	14	-	nC
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 20 V; V _{GS} = 10 V;	-	10	15	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13	-	6.4	10	nC
Q _{GS(th-pl)}	post-threshold gate- source charge	1	-	3.6	6	nC
Q _{GD}	gate-drain charge	1	-	5	10	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 20 V; <u>Fig. 12</u> ; <u>Fig. 13</u>	-	4.5	-	V

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
C _{iss}	input capacitance	V _{DS} = 20 V; V _{GS} = 0 V; f = 1 MHz;		-	2318	3245	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		-	785	1099	pF
C _{rss}	reverse transfer capacitance			-	114	251	pF
t _{d(on)}	turn-on delay time	V_{DS} = 20 V; R_L = 0.8 Ω ; V_{GS} = 10 V;		-	10	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	7	-	ns
t _{d(off)}	turn-off delay time			-	18	-	ns
t _f	fall time			-	7	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 20 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$		-	24.1	-	nC
Source-dra	ain diode			-	'		
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 15</u>		-	0.83	1.2	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$		-	25	-	ns
Q _r	recovered charge	V _{DS} = 20 V; <u>Fig. 16</u>	[1]	-	16	-	nC
t _a	reverse recovery rise time			-	14	-	ns
t _b	reverse recovery fall time			-	11	-	ns

[1] includes capacitive recovery

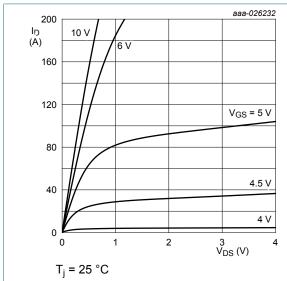


Fig. 7. Output characteristics; drain current as a function of drain-source voltage; typical values

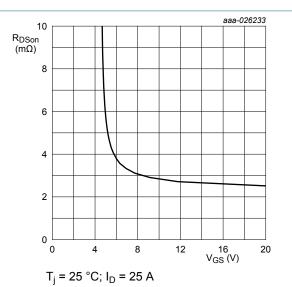


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

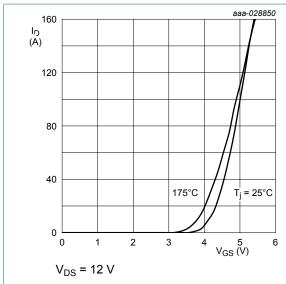


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

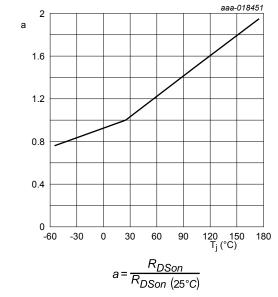


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

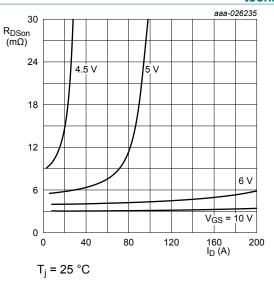


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

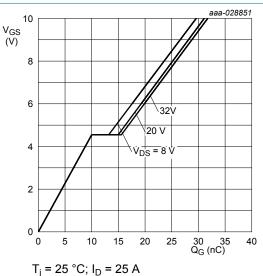


Fig. 12. Gate-source voltage as a function of gate charge; typical values

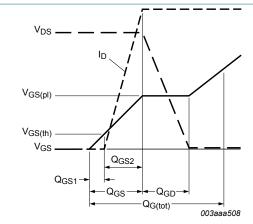
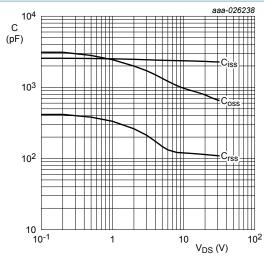


Fig. 13. Gate charge waveform definitions



 $V_{GS} = 0 V$; f = 1 MHz

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

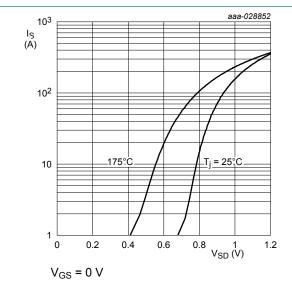


Fig. 15. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

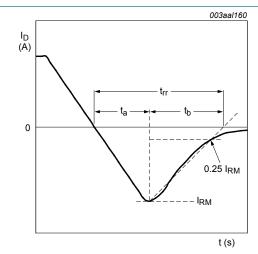


Fig. 16. Reverse recovery timing definition

11. Package outline

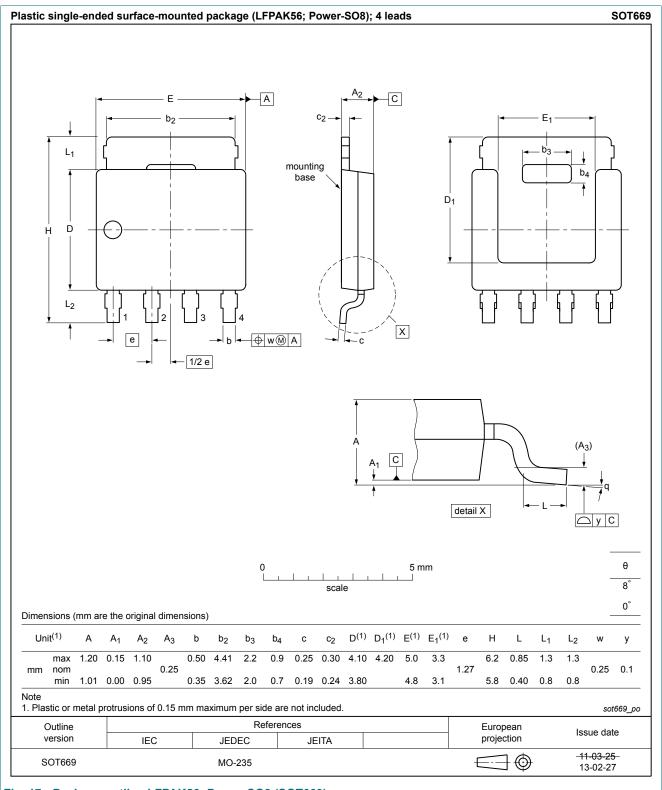
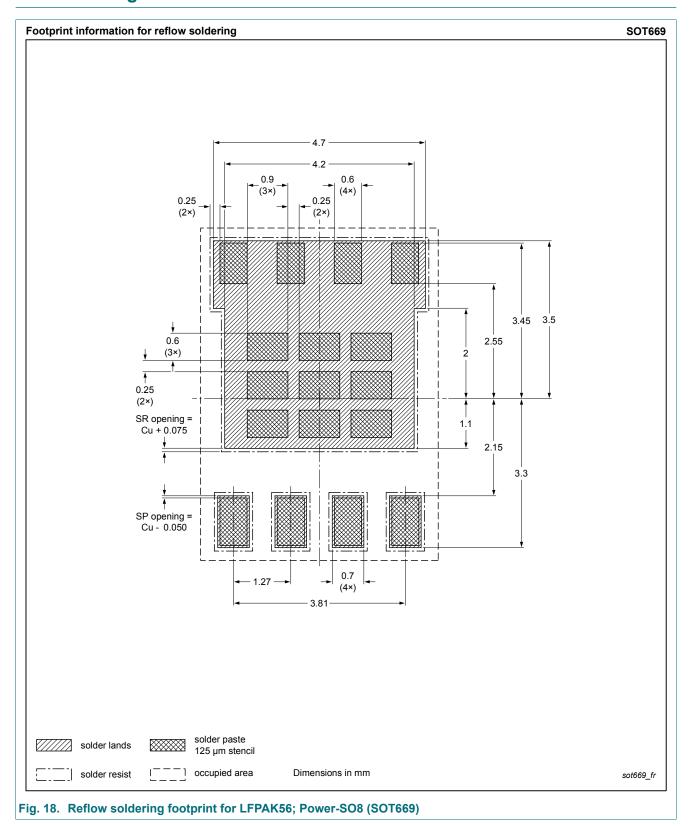


Fig. 17. Package outline LFPAK56; Power-SO8 (SOT669)

12. Soldering



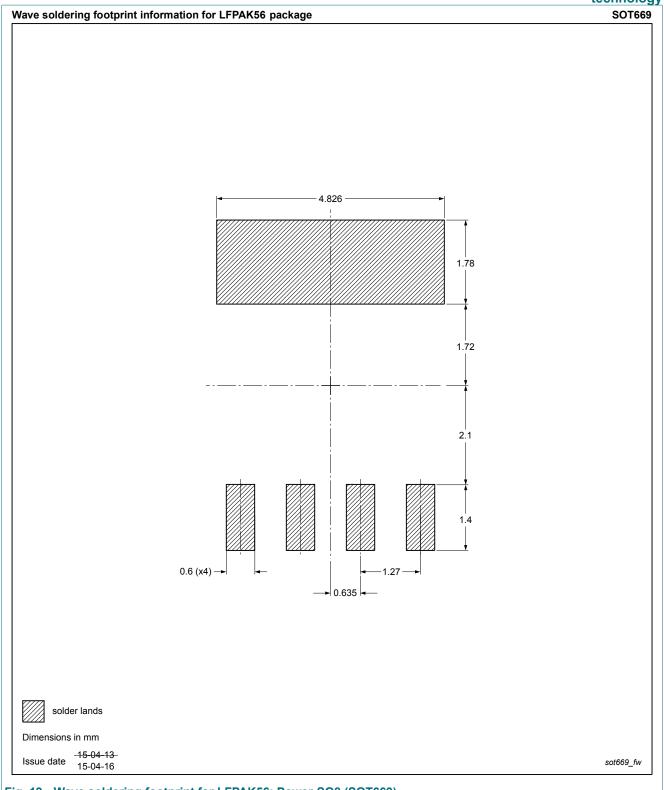


Fig. 19. Wave soldering footprint for LFPAK56; Power-SO8 (SOT669)

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